



DDR4

K4A8G165WB-BIWE



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Exceptional speed, high reliability, low energy consumption

High-performing memory empowers faster, powerful solutions. Samsung DDR4 delivers top speed with better bandwidth and reliability using less energy.

Specifications

Density	8 Gb	Org.	512M x 16
Speed	3200 Mbps	Voltage	1.2 V
Temp.	-40 ~ 95 °C	Package	96FBGA
Product Status	Mass Production		

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DDR4 Device Operation & Timing Diagram

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All product specifications reflect internal test results and are subject to variations by user's system configuration. All product images shown are for illustration purposes only and may not be an exact representation of the product. Samsung reserves the right to change product images and specifications at any time without notice.

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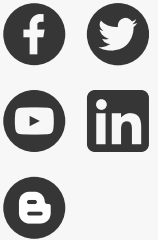
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